

STATE BOARD OF TECHNICAL EDUCATION AND TRAINING
TELANGANA:: HYDERABAD

From

The Secretary,
State Board of Technical Education
and Training, B.R.K.R. Bhavan,
7th Floor, Tank bund Road,
Hyderabad.

To

The Principals of all Govt/Aided/
Pvt. Polytechnics/2nd Shift Polytechnics in
Engineering Colleges.

Sir,

Sub: SBTET-Generation of Students PIN and Bio metric attendance IDs
– Certain instructions- issued– Regarding

Ref: Lr. No. SBTET-AAC/ATTN/1/2018-Academic Section -2 Dated: 30-05-2019

All the Principals/OSDs of Government/Aided/Private Polytechnics and 2nd shift Polytechnics in Engineering Colleges are aware that the Class work has commenced from 19th June 2019. Further instructions were already issued to make sure that (Permanent Identification Numbers (PIN) of all the I year students admitted during the Academic Year 2019-20 be generated by using Aadhar based Biometric Authenticated in admission & attendance module by using POS devices /IRIS devices and mark BMA regularly.

It is further informed that the students have to give their attendance through POS devices /IRIS devices with a minimum gap of 6 hours in between Two punches. If the gap between the Two punches is less than 3 hours or there is a single punch, it will be treated as absent and if the gap between 3 hours to less than 6 hours, it will be treated as half day present.

The Principals are further informed that, those students PIN are not generated through the above procedure, they will be treated as absent until their PINs are generated and authenticated by using Aadhar and given attendance through POS/IRIS devices, as the manual attendance has been dispensed.

All the Principals are requested to follow and implement the above instructions without fail.

For clarifications call help desk no: 040-23222192 during working hours (or) mail to sbtet-helpdesk@telangana.gov.in.

Yours faithfully,

Signature valid
Digitally signed by: SURESH UVSN
Date: 2019.06.20 13:14:30 BDT
Reason: Approved

SECRETARY

Copy submitted to Commissioner of Technical Education, TS.
for favour of kind information.